

FORM PTO-1449
(REV. 7-80)U.S. DEPARTMENT OF COMMERCE
PATENT AND TRADEMARK OFFICEATTY. DOCKET NO.
00P9119USSERIAL NO.
TBD**LIST OF DOCUMENTS CITED BY APPLICANT**
(Use several sheets if necessary)

APPLICANT

Jingyu Lian, et al.FILING DATE
HerewithGROUP
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U.S. PATENT DOCUMENTS

*EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE (IF APPROPRIATE)
	AA						
	AB						
	AC						
	AD						
	AE						
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
							YES	NO
EO	AL	10-242078	Publication Date: 9/11/1998	Japan			X	
	AM							
	AN							

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

EO	AO	D.E. Kotecki, et al., (Ba,Sr)TiO ₃ dielectrics for future stacked-capacitor DRAM, IJB J. Res. Develop, Vol. 43, No. 3, May 1999, pp. 367-379.
	AP	
	AQ	

EXAMINER

Edgardo Gutierrez

DATE CONSIDERED

6/6/02

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.